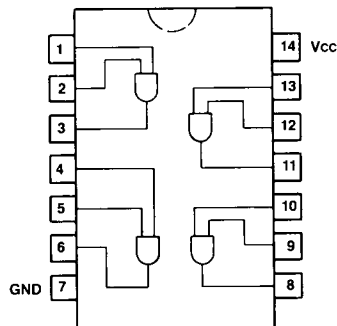


Quad 2-Input Positive AND Gate

The LS08 is a bipolar, NPN, sealed-junction, silicon integrated circuit. It is manufactured in low-power Schottky technology and is available in a wire-bonded, 14-pin plastic DIP or surface mount package.



Electrical Characteristics

$V_{CC} = 5.0 \pm 0.5 \text{ V}$, $T_A = -55 \text{ to } +125^\circ\text{C}$ (WA-LS)

$V_{CC} = 5.0 \pm 0.25 \text{ V}$, $T_A = 0 \text{ to } 70^\circ\text{C}$ (WP90222L5)

$V_{CC} = 5.0 \pm 0.5 \text{ V}$, $T_A = -40 \text{ to } +85^\circ\text{C}$ (WA-LSD, WP91397L5)

Parameter	Symbol	WA-LS		WP, WA-LSD		Units
		Min	Max	Min	Max	
Output Voltage, $V_{CC} = 4.5 \text{ V}$ (WA-LS), 4.75 V (WP, WA-LSD)						
Low, $I_{OL} = 4.0 \text{ mA}$	V_{OL}	—	0.4	—	0.4	V
$I_{OL} = 8.0 \text{ mA}$	V_{OL}	—	0.5	—	0.5	V
High, $I_{OH} = -0.4 \text{ mA}$	V_{OH}	2.5	—	2.7	—	V
Input Voltage, $V_{CC} = 4.5 \text{ V}$ (WA-LS), 4.75 V (WP, WA-LSD)						
Low	V_{iL}	—	0.7	—	0.8*	V
High	V_{iH}	2.0	7.5	2.0	5.5	V
Clamp, $I_{iN} = -18.0 \text{ mA}$	V_{iK}	—	-1.5	—	-1.5	V
Input Current, $V_{CC} = 5.5 \text{ V}$ (WA-LS), 5.25 V (WP, WA-LSD)						
Low, $V_{iL} = 0.4 \text{ V}$	I_{iL}	—	-0.4	—	-0.4	mA
High, $V_{iH} = 2.7 \text{ V}$	I_{iH}	—	20.0	—	20.0	μA
@ V_i max, $V_i = 7.0 \text{ V}$ (WA-LS), 5.5 V (WP, WA-LSD)	I_i	—	0.1	—	0.1	mA
Output Current, $V_{CC} = 5.5 \text{ V}$ (WA-LS), 5.25 V (WP, WA-LSD)						
Short-Circuit	I_{OS}	-20.0	-100.0	-20.0	-100.0	mA
Supply Current, $V_{CC} = 5.5 \text{ V}$ (WA-LS), 5.25 V (WP, WA-LSD)						
Output Low	I_{CCL}	—	8.8	—	8.8	mA
Output High	I_{CCH}	—	4.8	—	4.8	mA

* WA-LSD, WP91397L5: $V_{iL} = 0.7 \text{ V}$

